

# **isc Silicon NPN Power Transistor**

# BD301

### DESCRIPTION

- DC Current Gain -
- : h<sub>FE</sub> =30(Min.)@ I<sub>C</sub>= 3A
- Collector-Emitter Breakdown Voltage-: V<sub>(BR)CEO</sub>= 45V(Min.)
- Complement to Type BD302
- Minimum Lot-to-Lot variations for robust device performance and reliable operation

#### **APPLICATIONS**

• Designed for audio output stages up to 25W, vertical deflection circuits in color TV receivers.

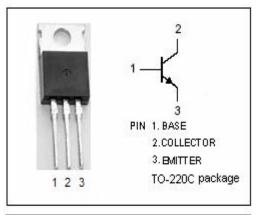
#### ABSOLUTE MAXIMUM RATINGS(Ta=25°C)

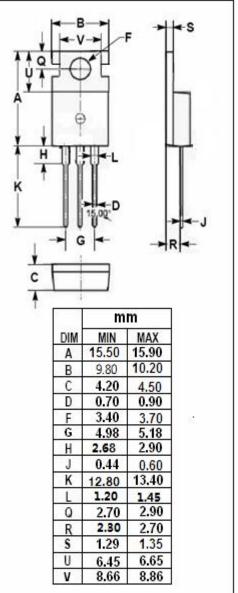
SYMBOL	PARAMETER	VALUE	UNIT
V <sub>CBO</sub>	Collector-Base Voltage	60	V
V <sub>CEO</sub>	Collector-Emitter Voltage	45	V
$V_{\text{EBO}}$	Emitter-Base Voltage	5	V
Ic	Collector Current-Continuous	8	А
Ісм	Collector Current-Peak	12	А
I <sub>B</sub>	Base Current-Continuous	2	А
Pc	Collector Power Dissipation @ $T_c=25^{\circ}C$	55	W
TJ	Junction Temperature	150	°C
T <sub>stg</sub>	Storage Temperature Range	-65~150	°C

#### **THERMAL CHARACTERISTICS**

SYMBOL	PARAMETER	МАХ	UNIT
R <sub>th j-c</sub>	Thermal Resistance, Junction to Case		°C/W

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isc website: www.iscsemi.com

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## ELECTRICAL CHARACTERISTICS

### $T_{c}\text{=}25^{\circ}\!\!\!\mathrm{C}$ unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN	МАХ	UNIT
V <sub>(BR)CEO</sub>	Collector-Emitter Breakdown Voltage	I <sub>C</sub> = 30mA; I <sub>B</sub> = 0	45		V
V <sub>CE(sat)</sub>	Collector-Emitter Saturation Voltage	I <sub>C</sub> = 3A; I <sub>B</sub> = 0.3A		1.0	V
V <sub>BE(sat)</sub>	Base-Emitter Saturation Voltage	I <sub>C</sub> = 3A; I <sub>B</sub> = 0.3A		1.5	V
I <sub>CEO</sub>	Collector Cutoff Current	V <sub>CE</sub> = 30V; I <sub>B</sub> = 0		1.0	mA
Ісво	Collector Cutoff Current	V <sub>CB</sub> = 40V; I <sub>E</sub> = 0; T <sub>C</sub> = 150°C		1.0	mA
I <sub>EBO</sub>	Emitter Cutoff Current	V <sub>EB</sub> = 5V; I <sub>C</sub> = 0		5.0	mA
h <sub>FE</sub>	DC Current Gain	I <sub>C</sub> = 3A; V <sub>CE</sub> = 2V	30		
f⊤	Current-Gain—Bandwidth Product	I <sub>C</sub> = 0.3A; V <sub>CE</sub> = 3V	3		MHz

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